LESD3Z5.0C

Transient Voltage Suppressors for ESD protection

DESCRIPTION

The LESD3Z5.0C is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

FEATURES

- ✧IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- ✧IEC61000-4-4 (EFT) 40A (5/50ηs)
- ✧Peak power dissipation: 100W (8/20μs)
- ✧Protects one directional I/O line
- ✧Low clamping voltage
- ✧Working voltages : 5V
- ✧Low leakage current

MACHANICAL DATA

- ✧SOD-323 package
- ✧Terminals: Gold plated, solderable per MIL-STD-750, method 2026
- ✧Packaging: Tape and Reel
- ✧Reel size: 7 inch

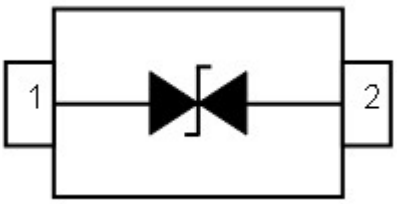
ORDERING INFORMATION

- ✧Device: LESD3Z5.0C
- ✧Package: SOD-323
- ✧Marking: 3M or AC
- ✧Material: Halogen free
- ✧Packing: Tape & Reel
- ✧Quantity per reel: 3,000pcs

APPLICATIONS

- ✧High Speed Line :USB1.0/2.0, VGA, DVI, SDI,
- ✧Serial and Parallel Ports
- ✧Notebooks, Desktops, Servers
- ✧Projection TV
- ✧Cellular handsets and accessories
- ✧Portable instrumentation
- ✧Peripherals

PIN CONFIGURATION



PACKAGE OUTLINE



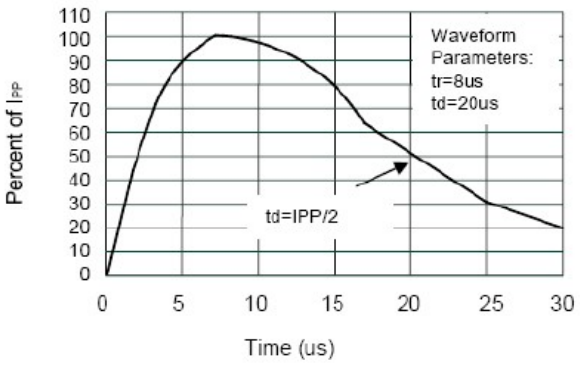
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
V_{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±30 ±30	kV
P_{PP}	Peak Pulse Power (8/20μs)	100	W
T_{OPT}	Operating Temperature	-40~150	°C
T_{STG}	Storage Temperature	-40~150	°C

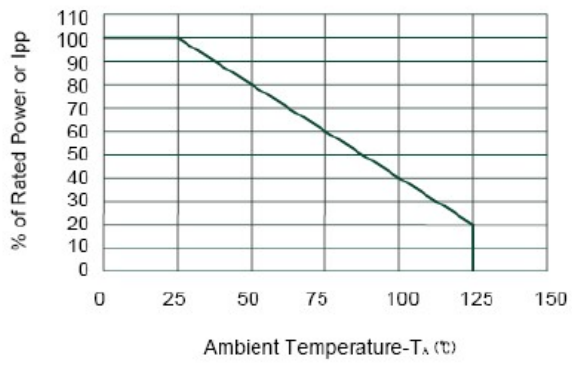
ELECTRICAL CHARACTERISTICS (Tamb=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V_{RWM}	Reverse Working Voltage				5.0	V
V_{BR}	Reverse Breakdown Voltage	I_T = 1mA	5.6		7.8	V
I_R	Reverse Leakage Current	V_{RWM} = 5V			1.0	μA
V_C	Clamping Voltage	I_{PP} = 5A, t_p = 8/20μs			11.6	V
V_C	Clamping Voltage	I_{PPmax} = 8A , t_p = 8/20μs			16.0	V
C_J	Junction Capacitance	V_R = 0V, f = 1MHz		10	15	pF

ELECTRICAL CHARACTERISTICS CURVE

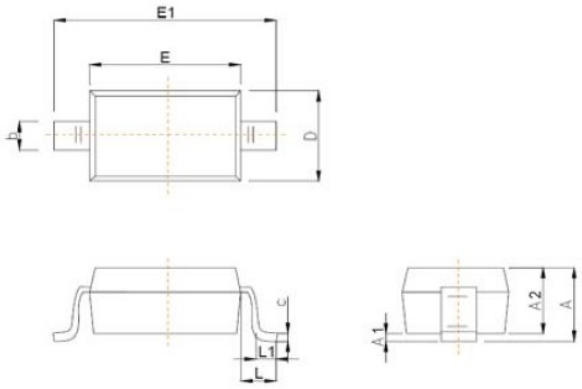


Pulse Waveform

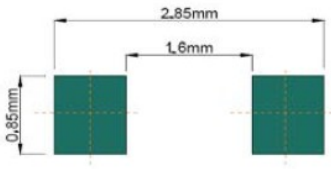


Power Derating Curve

SOD-323 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters	
	Min	Max
A		1.00
A1	0.000	0.100
A2	0.800	0.900
b	0.250	0.350
c	0.080	0.150
D	1.200	1.400
E	1.600	1.800
E1	2.500	2.700
e	1.800	2.040
L	0.475 REF	
L1	0.250	0.400
θ	0°	8°



Recommended Pad outline